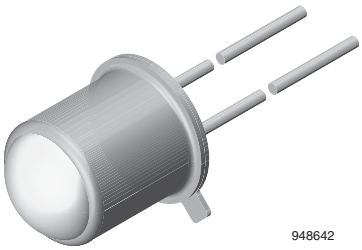
Silicon PIN Photodiode, RoHS Compliant



FEATURES

- Package type: leaded
- Package form: TO-18
- Dimensions (in mm): Ø 4.7
- Radiant sensitive area (in mm^2): 0.78
- High photo sensitivity
- High radiant sensitivity
- Suitable for visible and near infrared radiation
- Fast response times
- Angle of half sensitivity: $\varphi = \pm 12°$
- Hermetically sealed package
- Cathode connected to package
- Central chip alignment
- Compliant to RoHS Directive 2002/95/EC and in accordance with WEEE 2002/96/EC

Pb-free

e4

RoHS COMPLIANT

DESCRIPTION

BPW24R is a high sensitive silicon planar photodiode in a standard TO-18 hermetically sealed metal case with a glass lens.

A precise alignment of the chip gives a good coincidence of mechanical and optical axes. The device features a low capacitance and high speed even at low supply voltages.

APPLICATIONS

- High speed photo detector

PRODUCT SUMMARY			
COMPONENT	I_{ra} (A)	φ (deg)	$\lambda_{0.1}$ (nm)
BPW24R	60	± 12	400 to 1100

Note

- Test condition see table “Basic Characteristics”

ORDERING INFORMATION			
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
BPW24R	Bulk	MOQ: 1000 pcs, 1000 pcs/bulk	TO-18

Note

- MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V_R	60	V
Power dissipation	$T_{amb} \leq 25$ °C	P_V	210	mW
Junction temperature		T_j	125	°C
Operating temperature range		T_{amb}	- 40 to + 125	°C
Storage temperature range		T_{stg}	- 40 to + 125	°C
Soldering temperature	t ≤ 5 s	T_{sd}	260	°C
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm^2	R_{thJA}	350	K/W

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)						
PARAMETER	**TEST CONDITION**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Breakdown voltage	I_R = 100 µA, E = 0	$V_{(BR)}$	60	200		V
Reverse dark current	V_R = 50 V, E = 0	I_{ro}		2	10	nA
Diode capacitance	V_R = 0 V, f = 1 MHz, E = 0	C_D		11		pF
	V_R = 5 V, f = 1 MHz, E = 0	C_D		3.8		pF
	V_R = 20 V, f = 1 MHz, E = 0	C_D		2.5		pF
Open circuit voltage	E_e = 1 mW/cm², λ = 950 nm	V_o		450		mV
Temperature coefficient of V_o	E_e = 1 mW/cm², λ = 950 nm	TK_{Vo}		- 2		mV/K
Short circuit current	E_e = 1 mW/cm², λ = 950 nm	I_k		55		µA
Temperature coefficient of I_k	E_A = 1 klx	TK_{Ik}		0.1		%/K
Reverse light current	E_e = 1 mW/cm², λ = 950 nm, V_R = 20 V	I_{ra}	45	60		µA
Absolute Spectral Sensitivity	V_R = 5 V, λ = 870 nm	s(λ)		0.60		A/W
	V_R = 5 V, λ = 900 nm	s(λ)		0.55		A/W
Angle of half sensitivity		φ		± 12		deg
Wavelength of peak sensitivity		$λ_p$		900		nm
Range of spectral bandwidth		$λ_{0.1}$	400		1100	nm
Rise time	V_R = 20 V, R_L = 50 Ω, λ = 820 nm	t_r		7		ns
Fall time	V_R = 20 V, R_L = 50 Ω, λ = 820 nm	t_f		7		ns

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

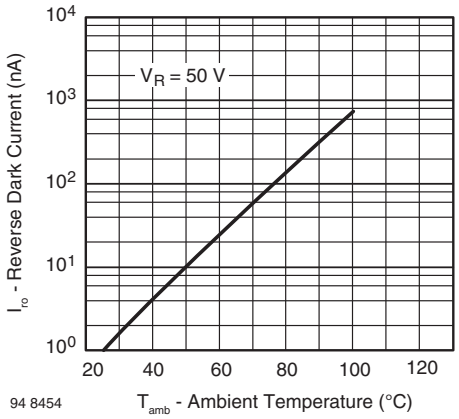


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

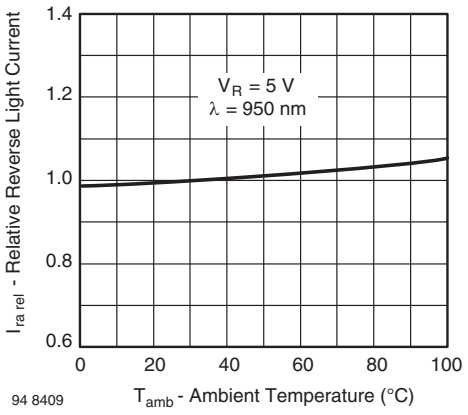


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

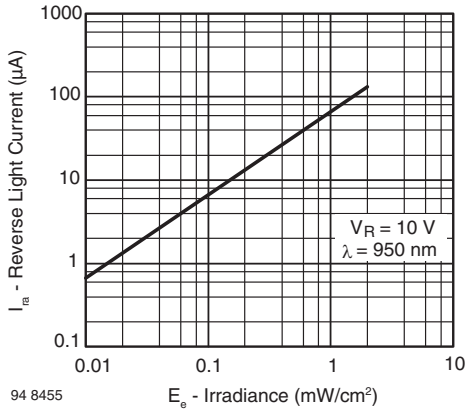


Fig. 3 - Reverse Light Current vs. Irradiance

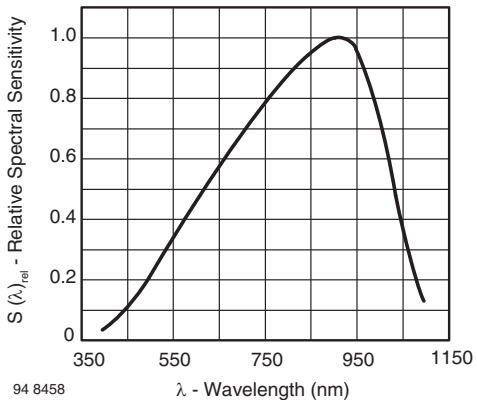


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

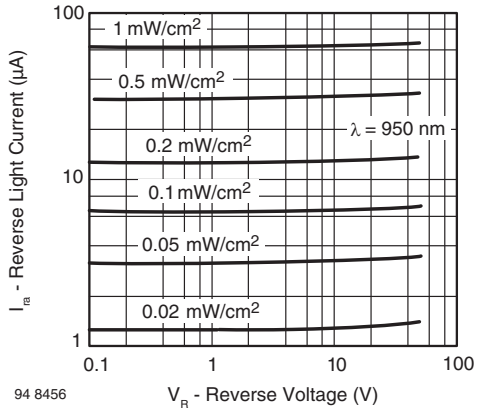


Fig. 4 - Reverse Light Current vs. Reverse Voltage

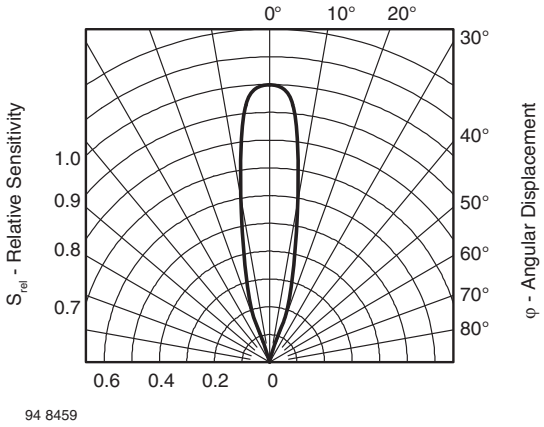


Fig. 7 - Relative Radiant Sensitivity vs. Angular Displacement

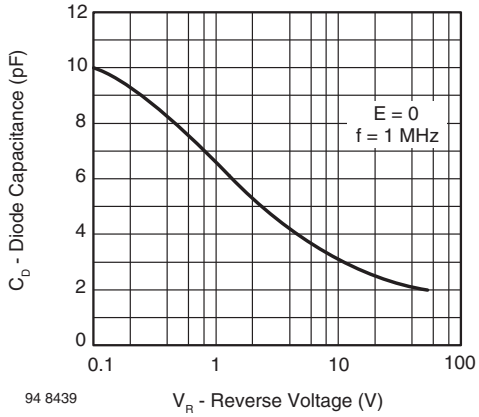
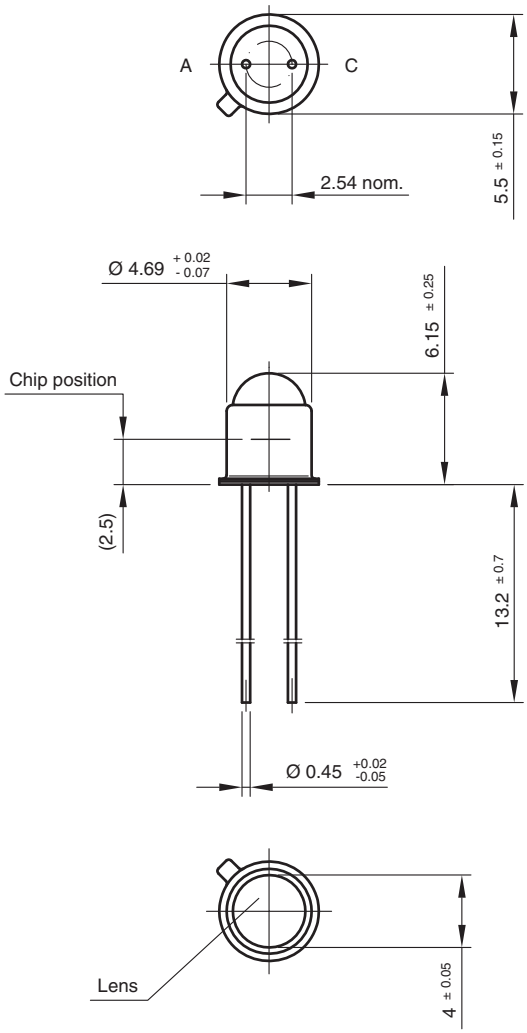
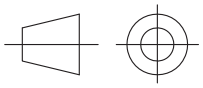


Fig. 5 - Diode Capacitance vs. Reverse Voltage

PACKAGE DIMENSIONS in millimeters





technical drawings
according to DIN
specifications

Drawing-No.: 6.503-5022.02-4

Issue: 1; 24.08.98

14487

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